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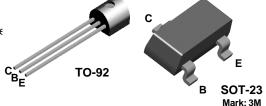
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2N5210/MMBT5210

NPN General Purpose Amplifier

This device is designed for low noise, high gain, general purpose amplifier applications at collector currents from 1µA to 50 mA.



Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	50	V	
V _{CBO}	Collector-Base Voltage	50	V	
V _{EBO}	Emitter-Base Voltage	4.5	V	
I _C	Collector Current - Continuous	100	mA	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Ma	Units	
		2N5210	MMBT5210	Office
P_{D}	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

(continued)

4.0

900

2.0

3.0

250

рF

dΒ

dΒ

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			<i>_</i>			

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAI	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage I _C = 1.0 mA, I _B = 0		50		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 0.1 \text{ mA}, I_E = 0$	50		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 35 \text{ V}, I_{E} = 0$		50	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		50	nA
h _{FE}	DC Current Gain	$I_C = 100 \mu\text{A}, V_{CE} = 5.0 \text{V}$	200	600	
1.5		$I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	250		
\/	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}^*$ $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$	250	0.7	V
V _{CE(sat)}	Base-Emitter On Voltage	$I_C = 1.0 \text{ mA}, I_B = 1.0 \text{ mA}$		0.85	V
V _{BE(on)}	Date Emilior on Vollage	10 - 110 1111 (, VCE - 0.0 V		0.00	•
SMALL SI	GNAL CHARACTERISTICS				

 $V_{CB} = 5.0 \text{ V}, I_E = 0, f = 100 \text{ kHz}$

 $R_S = 22 \text{ k}\Omega$, f = 10 Hz to 15.7 kHz

 $I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 1.0 kHz

 $I_C = 20 \ \mu A, \ V_{CE} = 5.0 \ V,$

 $I_{C} = 20 \mu A$, $V_{CE} = 5.0 V$, $R_{S} = 10 k\Omega$, f = 1.0 kHz

Noise Figure

Collector-Base Capacitance

Small-Signal Current Gain

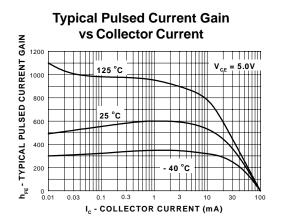
 C_{cb}

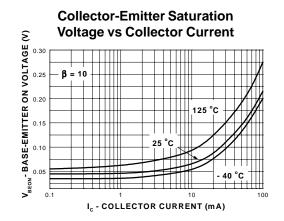
h_{fe} NF

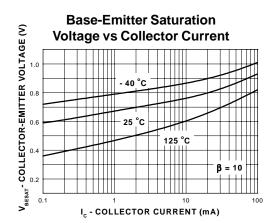
^{*}Pulse Test: Pulse Width $\leq\!300~\mu\text{s},$ Duty Cycle $\leq\!2.0\%$

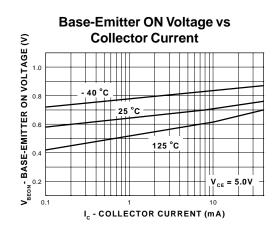
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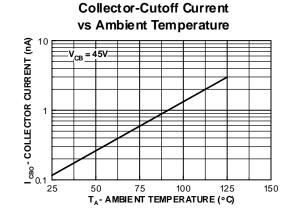
Typical Characteristics







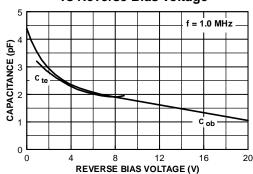




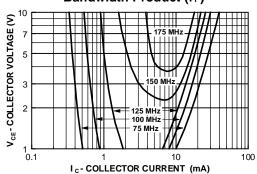
(continued)

Typical Characteristics (continued)

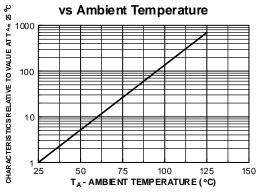




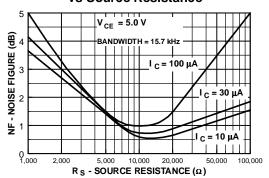
Contours of Constant Gain Bandwidth Product (f_T)



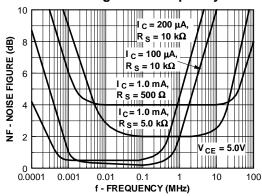
Normalized Collector-Cutoff Current



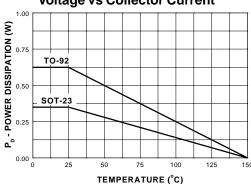
Wideband Noise Frequency vs Source Resistance



Noise Figure vs Frequency



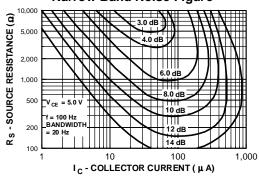
Base-Emitter Saturation Voltage vs Collector Current



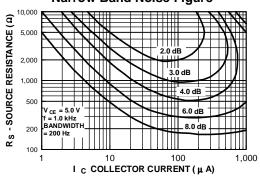
(continued)

Typical Characteristics (continued)

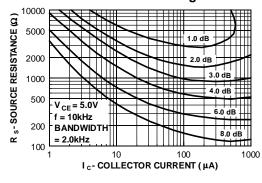
Contours of Constant Narrow Band Noise Figure



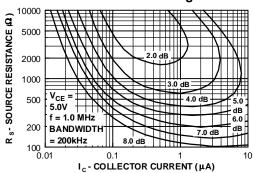
Contours of Constant Narrow Band Noise Figure



Contours of Constant Narrow Band Noise Figure



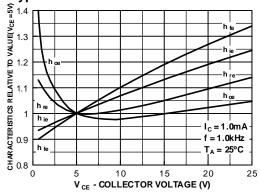
Contours of Constant Narrow Band Noise Figure



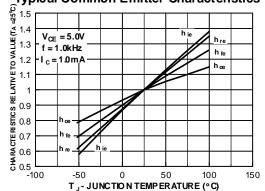
(continued)

Typical Common Emitter Characteristics (f = 1.0 kHz)

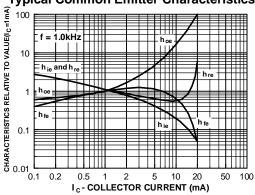
Typical Common Emitter Characteristics



Typical Common Emitter Characteristics



Typical Common Emitter Characteristics



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